

isc N-Channel Mosfet Transistor

75N08
• FEATURES

- Drain Current $I_D = 75A$ @ $T_C = 25^\circ C$
- Drain Source Voltage : $V_{DSS} = 80V$ (Min)
- Fast Switching Speed
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

• APPLICATIONS

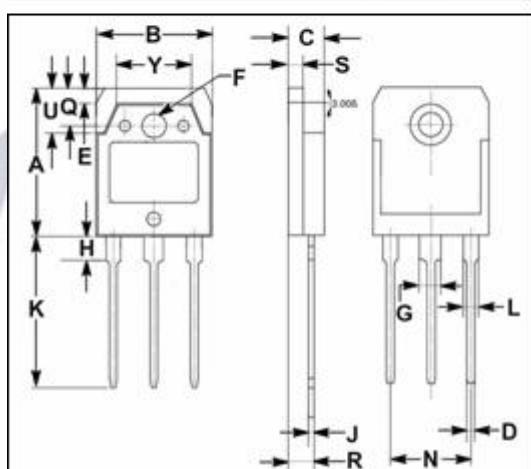
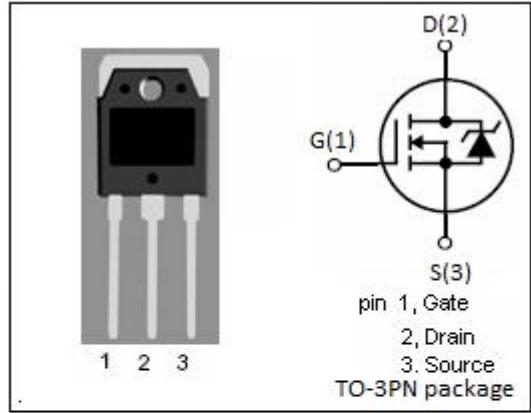
- Switching mode power supplies
- General purpose power amplifier

• ABSOLUTE MAXIMUM RATINGS ($T_a = 25^\circ C$)

SYMBOL	PARAMETER	VALUE	UNIT
V_{DSS}	Drain-Source Voltage ($V_{GS}=0$)	80	V
V_{GS}	Gate-Source Voltage	± 20	V
I_D	Drain Current-continuous@ $T_C = 25^\circ C$	75	A
$I_{D(puls)}$	Pulse Drain Current	300	A
P_{tot}	Total Dissipation@ $T_C = 25^\circ C$	250	W
T_j	Max. Operating Junction Temperature	150	$^\circ C$
T_{stg}	Storage Temperature Range	-65~150	$^\circ C$

• THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
$R_{th j-c}$	Thermal Resistance, Junction to Case	0.5	$^\circ C/W$
$R_{th j-a}$	Thermal Resistance, Junction to Ambient	80	$^\circ C/W$



DIM	mm	
	MIN	MAX
A	19.60	20.30
B	15.50	15.70
C	4.70	4.90
D	0.90	1.10
E	1.90	2.10
F	3.40	3.60
G	2.90	3.20
H	3.20	3.40
J	0.595	0.605
K	19.80	20.70
L	1.90	2.20
N	10.89	10.91
Q	4.90	5.10
R	3.35	3.45
S	1.995	2.100
U	5.90	6.20
Y	9.90	10.10

isc N-Channel Mosfet Transistor**75N08****ELECTRICAL CHARACTERISTICS** $T_c=25^\circ\text{C}$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYPE	MAX	UNIT
$V_{(\text{BR})\text{DSS}}$	Drain-Source Breakdown Voltage	$V_{GS}= 0$; $I_D= 250\mu\text{A}$	80			V
$V_{GS(\text{th})}$	Gate Threshold Voltage	$V_{DS}= V_{GS}$; $I_D=250\mu\text{A}$	2.0		4.5	V
V_{SD}	Diode Forward On-Voltage	$I_S=75\text{A}$; $V_{GS}= 0$			1.5	V
$R_{DS(\text{on})}$	Drain-Source On-Resistance	$V_{GS}= 10\text{V}$; $I_D=40\text{A}$			0.02	Ω
I_{GSS}	Gate-Body Leakage Current	$V_{GS}= \pm 20\text{V}$; $V_{DS}= 0$			± 100	nA
I_{DSS}	Zero Gate Voltage Drain Current	$V_{DS}= 64\text{V}$; $V_{GS}= 0$			200	μA
t_r	Rise Time	$V_{GS}=10\text{V}$; $I_D=37.5\text{A}$; $V_{DD}=40\text{V}$; $R_L=50\ \Omega$			110	ns
$t_{d(on)}$	Turn-on Delay Time				90	
t_f	Fall Time				95	
$t_{d(off)}$	Turn-off Delay Time				200	